

NLSF308

Quad 2-Input AND Gate

The NLSF308 is an advanced high speed CMOS 2-input AND gate fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7.0 V, allowing the interface of 5.0 V systems to 3.0 V systems.

Features

- High Speed: $t_{PD} = 4.3 \text{ ns}$ (Typ) at $V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 2.0 \mu\text{A}$ (Max) at $T_A = 25^\circ\text{C}$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2.0 V to 5.5 V Operating Range
- Low Noise: $V_{OLP} = 0.8 \text{ V}$ (Max)
- Function Compatible with Other Standard Logic Families
- QFN-16 Package
- Latchup Performance Exceeds 300 mA
- ESD Performance: Human Body Model; > 2000 V;
Machine Model; > 200 V
- Chip Complexity: 24 FETs or 6 Equivalent Gates
- Pb-Free Package is Available*

FUNCTION TABLE

Inputs		Output
A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H



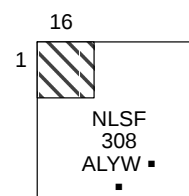
ON Semiconductor®

<http://onsemi.com>



QFN-16
MN SUFFIX
CASE 485G

MARKING DIAGRAM



NLSF308 = Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NLSF308MNR2	QFN-16	3000 / Tape & Reel
NLSF308MNR2G	QFN-16 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NLSF308

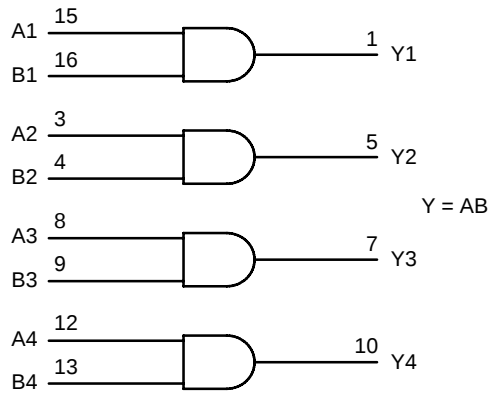


Figure 1. LOGIC DIAGRAM

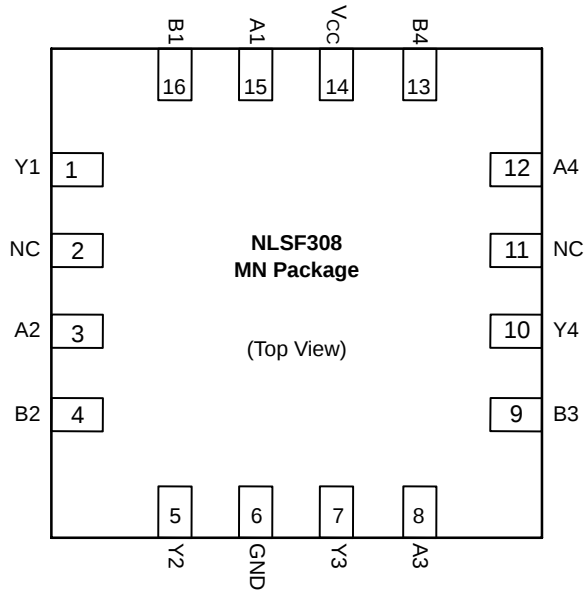


Figure 2. PIN ASSIGNMENT (QFN-16)

MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
DC Supply Voltage	V_{CC}	-0.5 to + 7.0	V
DC Input Voltage	V_{in}	-0.5 to + 7.0	V
DC Output Voltage	V_{out}	-0.5 to $V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current, per Pin	I_{out}	±25	mA
DC Supply Current, V_{CC} and GND Pins	I_{CC}	±50	mA
Power Dissipation in Still Air	P_D	450	mW
Storage Temperature	T_{stg}	-65 to + 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Max	Unit
DC Supply Voltage	V_{CC}	2.0	5.5	V
DC Input Voltage	V_{in}	0	5.5	V
DC Output Voltage	V_{out}	0	V_{CC}	V
Operating Temperature	T_A	-40	+ 85	°C
Input Rise and Fall Time	t_r, t_f	0	100	ns/V
		0	20	

DC ELECTRICAL CHARACTERISTICS

Parameter	Test Conditions	Symbol	V _{CC} V	T _A = 25°C			T _A = - 40 to 85°C		Unit
				Min	Typ	Max	Min	Max	
Minimum High-Level Input Voltage		V _{IH}	2.0 3.0 to 5.5	1.50 V _{CC} × 0.7			1.50 V _{CC} × 0.7		V
Maximum Low-Level Input Voltage		V _{IL}	2.0 3.0 to 5.5			0.50 V _{CC} × 0.3		0.50 V _{CC} × 0.3	V
Minimum High-Level Output Voltage	V _{in} = V _{IH} or V _{IL} I _{OH} = -50 μA	V _{OH}	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V
	V _{in} = V _{IH} or V _{IL} I _{OH} = -4 mA, I _{OH} = -8 mA		3.0 4.5	2.58 3.94			2.48 3.80		
Maximum Low-Level Output Voltage	V _{in} = V _{IH} or V _{IL} I _{OL} = 50 μA	V _{OL}	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
	V _{in} = V _{IH} or V _{IL} I _{OL} = 4 mA I _{OL} = 8 mA		3.0 4.5			0.36 0.36		0.44 0.44	
Maximum Input Leakage Current	V _{in} = 5.5 V or GND		0 to 5.5			± 0.1		± 1.0	μA
Maximum Quiescent Supply Current	V _{in} = V _{CC} or GND		5.5			2.0		20.0	μA

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3.0 ns)

Parameter	Test Conditions	Symbol	T _A = 25°C			T _A = – 40 to 85°C		Unit
			Min	Typ	Max	Min	Max	
Maximum Propagation Delay, A or B to Y	V _{CC} = 3.3 ± 0.3 V, C _L = 15 pF, C _L = 50 pF	t _{PLH} , t _{PHL}		6.2 8.7	8.8 12.3	1.0 1.0	10.5 14.0	ns
	V _{CC} = 5.0 ± 0.5 V, C _L = 15 pF, C _L = 50 pF			4.3 5.8	5.9 7.9	1.0 1.0	7.0 9.0	
Maximum Input Capacitance		C _{in}		4	10		10	pF
Power Dissipation Capacitance (Note 1)		C _{PD}	Typical @ 25°C, V _{CC} = 5.0 V					pF
			18					

1. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}/4 (per gate). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

NOISE CHARACTERISTICS (Input t_r = t_f = 3.0 ns, C_L = 50 pF, V_{CC} = 5.0 V)

Characteristic	Symbol	T _A = 25°C		Unit
		Typ	Max	
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	0.3	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	-0.3	-0.8	V
Minimum High Level Dynamic Input Voltage	V _{IHD}		3.5	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}		1.5	V

NLSF308

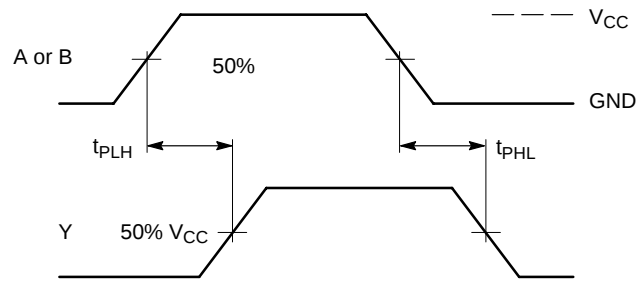
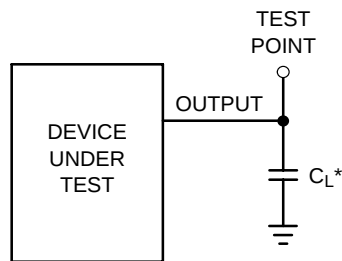


Figure 3. Switching Waveforms



*Includes all probe and jig capacitance

Figure 4. Test Circuit

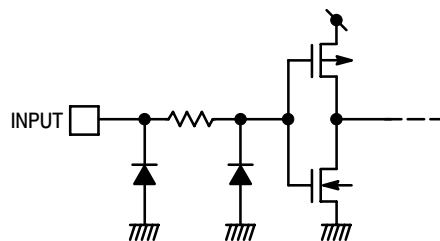


Figure 5. Input Equivalent Circuit

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9